TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74ACT540P,TC74ACT540F,TC74ACT540FT
TC74ACT541P,TC74ACT541F,TC74ACT541FT

Octal Bus Buffer

TC74ACT540P/F/FT	Inverting, 3-State Outputs
TC74ACT541P/F/FT	Non-Inverting, 3-State Outputs

The TC74ACT540/TC74ACT541 are advanced high speed CMOS OCTAL BUS BUFFERs fabricated with silicon gate and double-layer metal wiring C^2MOS technology.

They achieve the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

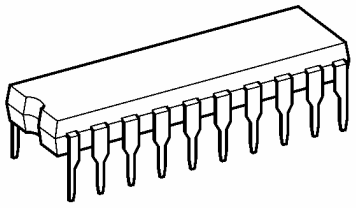
These devices may be used as a level converter for interfacing TTL or NMOS to High Speed CMOS. The inputs are compatible with TTL, NMOS and CMOS output voltage levels.

The TC74ACT540 is an inverting type, and the TC74ACT541 is a non-inverting type.

When either $\overline{G}1$ or $\overline{G}2$ are high, the terminal outputs are in the high-impedance state.

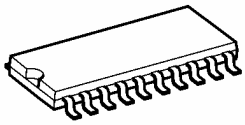
All inputs are equipped with protection circuits against static discharge or transient excess voltage.

TC74ACT540P, TC74ACT541P



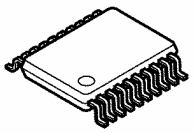
DIP20-P-300-2.54A

TC74ACT540F, TC74ACT541F



SOP20-P-300-1.27A

TC74ACT540FT, TC74ACT541FT



TSSOP20-P-0044-0.65A

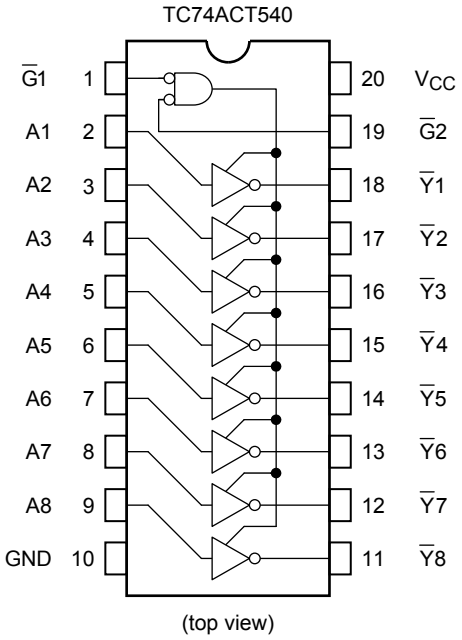
Weight

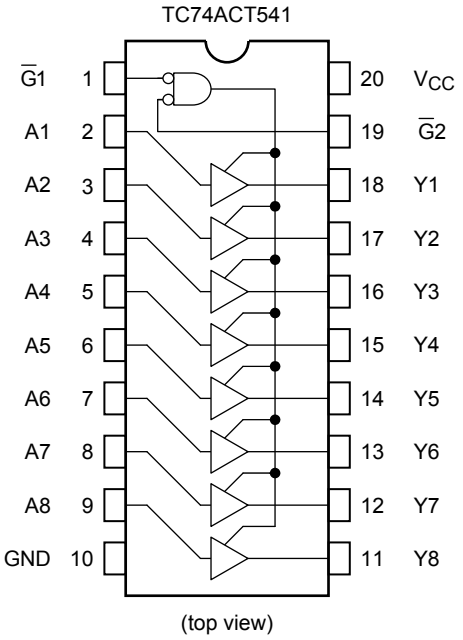
DIP20-P-300-2.54A	: 1.30 g (typ.)
SOP20-P-300-1.27A	: 0.22 g (typ.)
TSSOP20-P-0044-0.65A	: 0.08 g (typ.)

Features

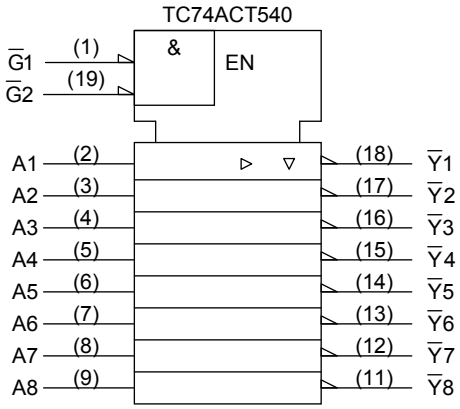
- High speed: t_{pd} = 4.3 ns (typ.) at V_{CC} = 5 V
- Low power dissipation: I_{CC} = 8 μA (max) at Ta = 25°C
- Compatible with TTL outputs
  : V_{IL} = 0.8 V (max) V_{IH} = 2.0 V (min)
- Symmetrical output impedance
  : $|I_{OH}| = I_{OL}$ = 24 mA (min)
  Capability of driving 50 Ω transmission lines.
- Balanced propagation delays: $t_{pLH} \simeq t_{pHL}$
- Pin and function compatible with 74F540/541

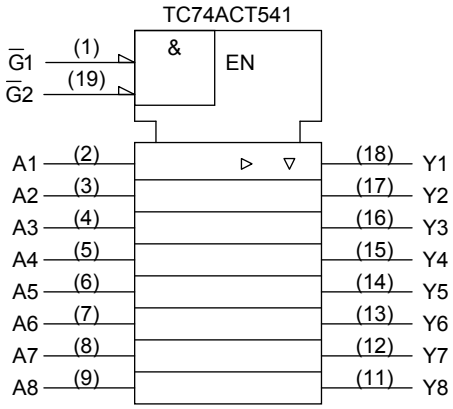
Pin Assignment





IEC Logic Symbol





Truth Table

Inputs			Outputs	
$\overline{G}1$	$\overline{G}2$	A_n	Y_n	$\overline{Y}_n$
H	X	X	Z	Z
X	H	X	Z	Z
L	L	H	H	L
L	L	L	L	H

X: Don't care

Z: High impedance

Y_n: ACT541

$\overline{Y}_n$: ACT540

Absolute Maximum Ratings (Note 1)

Characteristics	Symbol	Rating	Unit
Supply voltage range	V_{CC}	−0.5 to 7.0	V
DC input voltage	V_{IN}	−0.5 to V_{CC} + 0.5	V
DC output voltage	V_{OUT}	−0.5 to V_{CC} + 0.5	V
Input diode current	I_{IK}	±20	mA
Output diode current	I_{OK}	±50	mA
DC output current	I_{OUT}	±50	mA
DC V_{CC}/ground current	I_{CC}	±200	mA
Power dissipation	P_D	500 (DIP) (Note 2)/180 (SOP/TSSOP)	mW
Storage temperature	T_{stg}	−65 to 150	°C

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.
Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook (“Handling Precautions”/“Derating Concept and Methods”) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 2: 500 mW in the range of Ta = −40 to 65°C. From Ta = 65 to 85°C a derating factor of −10 mW/°C should be applied up to 300 mW.

Operating Ranges (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage	V_{CC}	4.5 to 5.5	V
Input voltage	V_{IN}	0 to V_{CC}	V
Output voltage	V_{OUT}	0 to V_{CC}	V
Operating temperature	T_{opr}	−40 to 85	°C
Input rise and fall time	dt/dV	0 to 10	ns/V

Note: The operating ranges must be maintained to ensure the normal operation of the device.
Unused inputs must be tied to either VCC or GND.

Electrical Characteristics

DC Characteristics

Characteristics	Symbol	Test Condition		V_{CC} (V)	Ta = 25°C Min	Ta = 25°C Typ.	Ta = 25°C Max	Ta = −40 to 85°C Min	Ta = −40 to 85°C Max	Unit
High-level input voltage	V_{IH}	—		4.5 to 5.5	2.0	—	—	2.0	—	V
Low-level input voltage	V_{IL}	—		4.5 to 5.5	—	—	0.8	—	0.8	V
High-level output voltage	V_{OH}	V_{IN} = V_{IH} or V_{IL}	I_{OH} = −50 μA	4.5	4.4	4.5	—	4.4	—	V
			I_{OH} = −24 mA	4.5	3.94	—	—	3.80	—	
			I_{OH} = −75 mA (Note)	5.5	—	—	—	3.85	—	
Low-level output voltage	V_{OL}	V_{IN} = V_{IH} or V_{IL}	I_{OL} = 50 μA	4.5	—	0.0	0.1	—	0.1	V
			I_{OL} = 24 mA	4.5	—	—	0.36	—	0.44	
			I_{OL} = 75 mA (Note)	5.5	—	—	—	—	1.65	
3-state output off-state current	I_{OZ}	V_{IN} = V_{IH} or V_{IL} V_{OUT} = V_{CC} or GND		5.5	—	—	±0.5	—	±5.0	μA
Input leakage current	I_{IN}	V_{IN} = V_{CC} or GND		5.5	—	—	±0.1	—	±1.0	μA
Quiescent supply current	I_{CC}	V_{IN} = V_{CC} or GND		5.5	—	—	8.0	—	80.0	μA
	I_C	Per input: V_{IN} = 3.4 V Other input: V_{CC} or GND		5.5	—	—	1.35	—	1.5	mA

Note: This spec indicates the capability of driving 50 Ω transmission lines.

One output should be tested at a time for a 10 ms maximum duration.

AC Characteristics (C_L = 50 pF, R_L = 500 Ω, input: $t_r = t_f$ = 3 ns)

Characteristics	Symbol	Test Condition		Ta = 25°C			Ta = −40 to 85°C		Unit
			V_{CC} (V)	Min	Typ.	Max	Min	Max	
Propagation delay time (Note 2)	t_{pLH} t_{pHL}	—	5.0 ± 0.5	—	5.0	8.3	1.0	9.5	ns
Propagation delay time (Note 3)	t_{pLH} t_{pHL}	—	5.0 ± 0.5	—	5.0	8.3	1.0	9.5	ns
Output enable time	t_{pZL} t_{pZH}	—	5.0 ± 0.5	—	7.3	11.4	1.0	13.0	ns
Output disable time	t_{pLZ} t_{pHZ}	—	5.0 ± 0.5	—	5.9	9.2	1.0	10.5	ns
Input capacitance	C_{IN}	—		—	5	10	—	10	pF
Output capacitance	C_{OUT}	—		—	10	—	—	—	pF
Power dissipation capacitance	C_{PD} (Note 1)	TC74ACT540		—	24	—	—	—	pF
		TC74ACT541		—	27	—	—	—	

Note 1: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

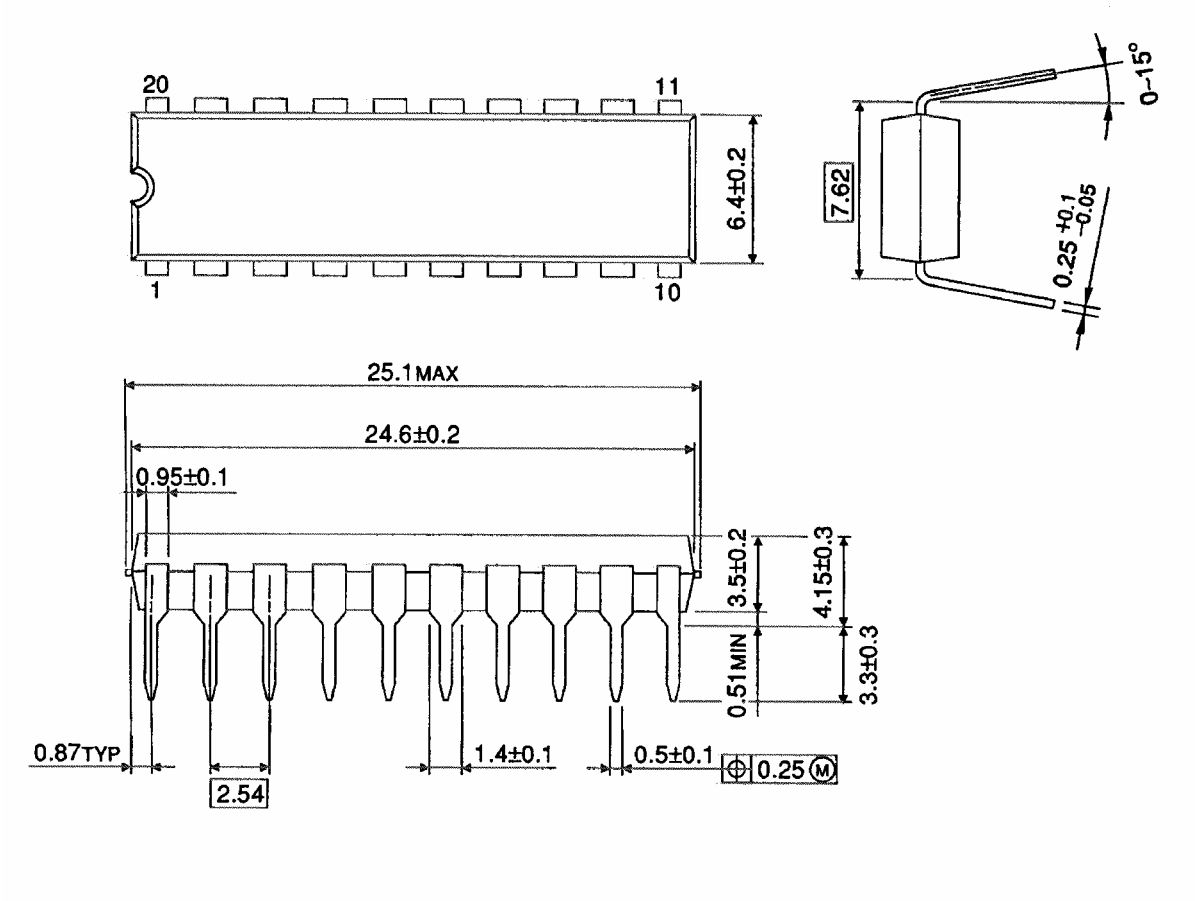
$$I_{CC\ (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/8 \text{ (per bit)}$$

Note 2: For TC74ACT540 only

Note 3: For TC74ACT541 only

Package Dimensions

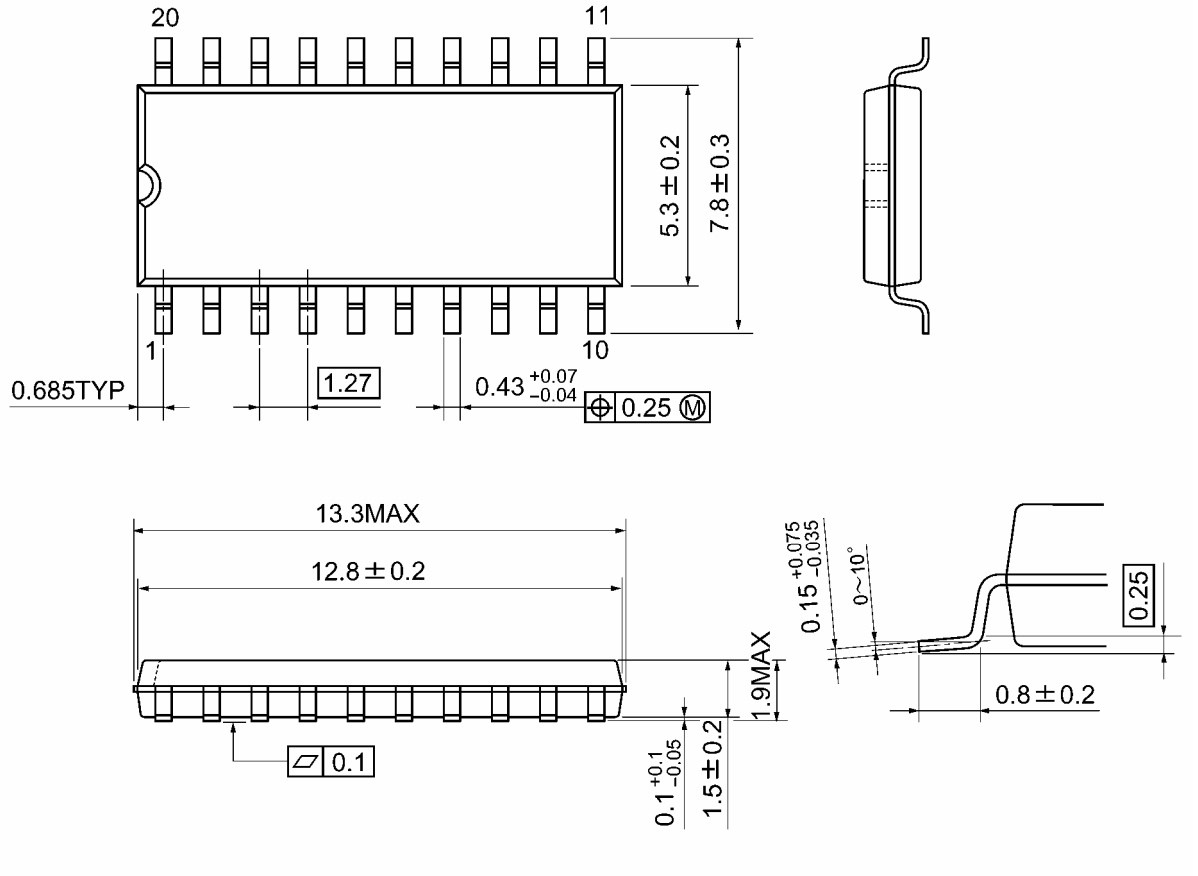
DIP20-P-300-2.54A Unit : mm



Weight: 1.30 g (typ.)

Package Dimensions

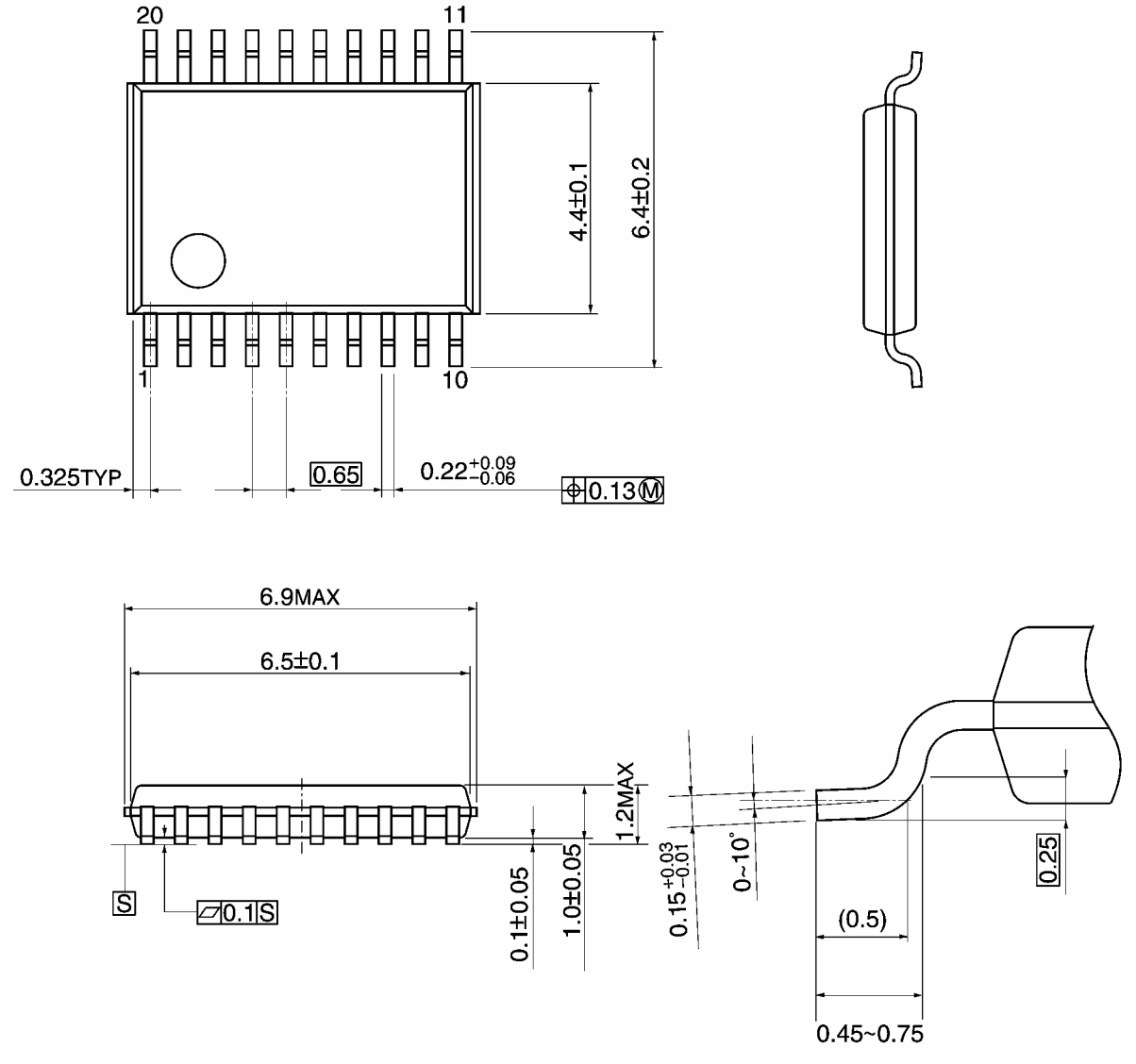
SOP20-P-300-1.27A Unit: mm



Weight: 0.22 g (typ.)

Package Dimensions

TSSOP20-P-0044-0.65A Unit: mm



Weight: 0.08 g (typ.)

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20070701-EN GENERAL

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